

**ON Semiconductor®** 

# NC7SZ00 TinyLogic<sup>®</sup> UHS Two-Input NAND Gate

### Features

- Ultra-High Speed: tPD 2.4ns (Typical) into 50pF at 5V Vcc
- High Output Drive: ±24mA at 3V V<sub>CC</sub>
- Broad Vcc Operating Range: 1.65V to 5.5V
- Matches Performance of LCX Operated at 3.3V Vcc
- Power Down High-Impedance Inputs/Outputs
- Over-Voltage Tolerance inputs facilitate 5V to 3V Translation
- Proprietary Noise/EMI Reduction Circuitry
- Ultra-Small MicroPak<sup>TM</sup> Packages
- Space-Saving SOT23 and SC70 Packages

### Description

The NC7SZ00 is a single two-input NAND gate from ON Semiconductor's Ultra-High Speed (UHS) series of TinyLogic<sup>®</sup>. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a broad  $V_{CC}$  operating range. The device is specified to operate over the 1.65V to 5.5V V<sub>CC</sub> operating range. The inputs and output are high impedance when V<sub>CC</sub> is 0V. Inputs tolerate voltages up to 6V, independent of V<sub>CC</sub> operating voltage.

Ordering	Information
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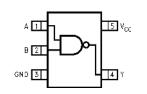
Part Number	Top Mark	Package	Packing Method
NC7SZ00M5X	7Z00	5-Lead SOT23, JEDEC MO-178 1.6mm	3000 Units on Tape & Reel
NC7SZ00P5X	Z00	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZ00L6X	YY	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZ00FHX	YY	6-Lead, MicroPak2™, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

### **Connection Diagrams**



Figure 1. Logic Symbol

### **Pin Configurations**



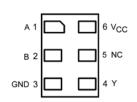
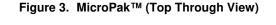


Figure 2. SC70 and SOT23 (Top View)

### **Pin Definitions**



Pin # SC70 / SOT23	Pin # MicroPak™	Name	Description
1	1	A	Input
2	2	В	Input
3	3	GND	Ground
4	4	Y Output	
5	6	Vcc	Supply Voltage
	5	NC	No Connect

### **Function Table**

Inputs		Output
A	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

H = HIGH Logic Level

L = LOW Logic Level

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Max.	Unit
Vcc	Supply Voltage		-0.5	6.0	V
VIN	DC Input Voltage		-0.5	6.0	V
Vout	DC Output Voltage		-0.5	6.0	V
1	DC Input Diode Current	V <sub>IN</sub> < -0.5V		-50	mA
I <sub>IK</sub>		V <sub>IN</sub> > 6.0V		+20	
	DC Outrast Diada Current	Vout < -0.5V		-50	- mA
Іок	DC Output Diode Current	$V_{OUT} > 6V, V_{CC}=GND$		+20	
I <sub>OUT</sub>	DC Output Current			±50	mA
Icc or Ignd	DC V <sub>CC</sub> or Ground Current			±50	mA
Tstg	Storage Temperature Range		-65	+150	°C

	TJ	Junction Temperature Under Bias		+150	°C
	ΤL	Junction Lead Temperature (Soldering, 10 Seconds)		+260	°C
	P <sub>D</sub> I		SOT-23	200	
		Dower Discipation at 85%	SC70-5	150	mW
		Power Dissipation at +85°C	MicroPak™-6	130	11100
			MicroPak2™-6	120	
	ESD	Human Body Model, JEDEC:JESD22-A114		4000	V
	ESD	Charge Device Model, JEDEC:JESD22-C101		2000	v

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions	Min.	Max.	Unit	
Vcc	Supply Voltage Operating		1.65	5.50	v	
VCC	Supply Voltage Data Retention		1.5	5.5	v	
VIN	Input Voltage		0	5.5	V	
Vout	Output Voltage		0	Vcc	V	
TA	Operating Temperature		-40	+85	°C	
	Input Rise and Fall Times	V <sub>cc</sub> at 1.8V, 2.5V ±0.2V	0	20	ns/V	
tr, tr		$V_{CC}$ at 3.3V ± 0.3V	0	10		
		$V_{CC}$ at 5.0V $\pm$ 0.5V	0	5		
		SOT-23		300		
0		SC70-5		435	•CM	
θја	Thermal Resistance	MicroPak <sup>™</sup> -6		500	°C/W	
		MicroPak2 <sup>™</sup> -6		560	1	

Note:

1. Unused inputs must be held HIGH or LOW. They may not float.

Symbol	Parameter	Vcc	Conditions	T <sub>A</sub> =25°C			T₄=-40 to +85°C		Units
				Min.	Тур.	Max.	Min.	Max.	
V		1.65 to 1.95		0.75V <sub>CC</sub>			$0.75V_{CC}$		V
VIH	HIGH Level Input Voltage	2.30 to 5.50		$0.70V_{CC}$			$0.70V_{CC}$		v
V		1.65 to 1.95				$0.25V_{CC}$		$0.25V_{\text{CC}}$	v
V <sub>IL</sub> LOW Level Input Voltage	2.30 to 5.50				$0.30V_{CC}$		$0.30V_{\text{CC}}$	v	
		1.65		1.55	1.65		1.55		
		1.80		1.70	1.80		1.70		
		2.30	V <sub>IN</sub> =V <sub>IL</sub> I <sub>OH</sub> =-100µA	2.20	2.30		2.20		
	HIGH Level Output Voltage	3.00		2.90	3.00		2.90		- V
N/		4.50		4.40	4.50		4.40		
V <sub>OH</sub>		1.65	I <sub>OH</sub> =-4mA	1.29	1.52		1.29		
		2.30	I <sub>OH</sub> =-8mA	1.90	2.15		1.90		
		3.00	I <sub>OH</sub> =-16mA	2.40	2.80		2.40		
		3.00	I <sub>OH</sub> =-24mA	2.30	2.68		2.30		
		4.50	I <sub>OH</sub> =-32mA	3.80	4.20		3.80		
	1.65	1.65			0.00	0.10		0.08	
		2.30			0.00	0.10		0.10	
		3.00	V <sub>IN</sub> =V <sub>IH</sub> I <sub>OL</sub> =100µA		0.00	0.10		0.10	
		3.00	10L-100µ/(		0.00	0.10		0.10	
V	LOW Level Output	4.50			0.00	0.10		0.10	V
V <sub>OL</sub>	Voltage	1.65	I <sub>OL</sub> =4mA		0.80	0.24		0.24	v
		2.30	I <sub>OL</sub> =8mA		0.10	0.30		0.30	
		3.00	I <sub>OL</sub> =16mA		0.15	0.40		0.40	
		3.00	I <sub>OL</sub> =24mA		0.22	0.55		0.55	
		4.50	I <sub>OL</sub> =32mA		0.22	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	0 to 5.5	V <sub>IN</sub> =5.5V, GND			±1		±10	μA
I <sub>OFF</sub>	Power Off	0	$V_{IN}$ or $V_{OUT}$ =5.5V			1		10	μA
Icc	Quiescent Supply Current	1.65 to 5.50	V <sub>IN</sub> =5.5V, GND			2		20	μA

Figure

Figure 4 Figure 5

Figure 6

pF

AC Ele	ctrical Charact	teristics								
O. make at	Demonster	N	O a maliti a ma	T,	a=25°C		T <sub>A</sub> =-40	to +85°C		Ī
Symbol	Parameter	Vcc	Conditions	Min.	Тур.	Max.	Min.	Max.	Units	
		1.65		2.0	5.4	11.4	2.0	12.0		Î
		1.80		2.0	4.5	9.5	2.0	10.0		
		2.50 ± 0.20	C <sub>L</sub> =15pF, B <sub>L</sub> =1MO	0.8	3.0	6.5	0.8	7.0		
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay	$3.30 \pm 0.30$	R <sub>L</sub> =1ΜΩ	0.5	2.4	4.5	0.5	4.7	ns	
		$5.00 \pm 0.50$		0.5	2.0	3.9	0.5	4.1		
		3.30 ± 0.30	C <sub>L</sub> =50pF,	1.5	2.9	5.0	1.5	5.2		
	5.0	$5.00 \pm 0.50$	R <sub>L</sub> =500Ω	0.8	2.4	4.3	0.8	4.5		
C <sub>IN</sub>	Input Capacitance	0.00			4				pF	Ī
_	Power Dissipation	3.30			24				_	I

Power Dissipation

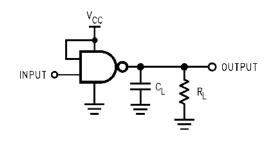
Capacitance<sup>(2)</sup>

#### Note:

 $C_{PD}$ 

2. CPD is defined as the value of the internal equivalent capacitance derived from dynamic operating current consumption (ICCD) at no output lading and operating at 50% duty cycle. CPD is related to ICCD dynamic operating current by the expression:  $I_{CCD}=(C_{PD})(V_{CC})(f_{IN})+(I_{CCS}tatic)$ .

30



5.00

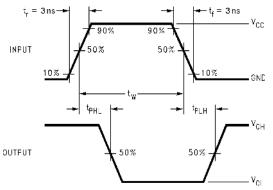
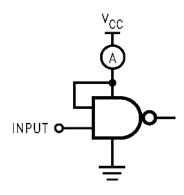


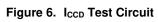
Figure 4. AC Test Circuit

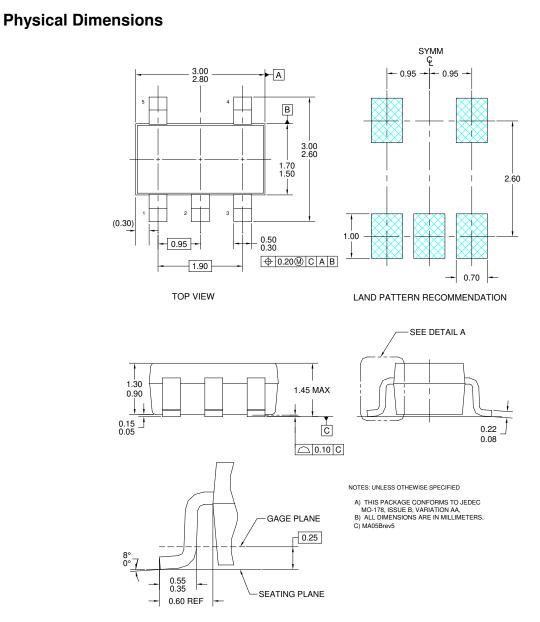




#### Note:

3. Input=AC Waveform; t<sub>r</sub>=t<sub>f</sub>=1.8ns; PRR=10MHz; Duty Cycle =50%.





#### Figure 7. 5-Lead SOT23, JEDEC MO-178 1.6mm

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Package Designator	Tape Section Cavity Number		Cavity Status	Cover Type Status	
	Leader (Start End)	125 (Typical)	Empty	Sealed	
M5X	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (Typical)	Empty	Sealed	

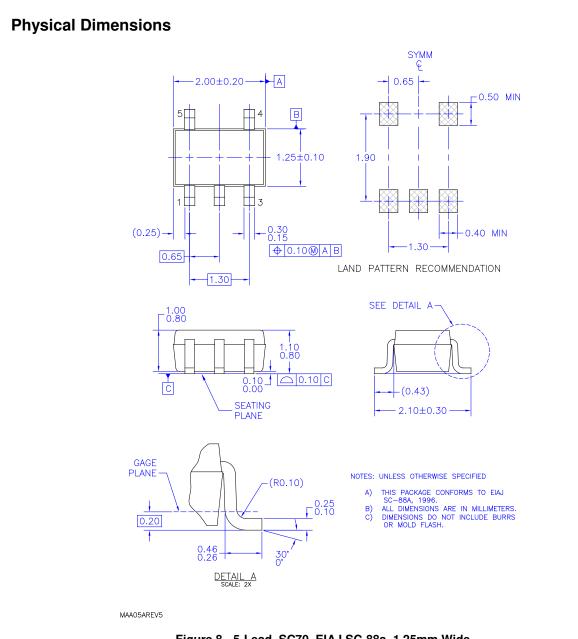
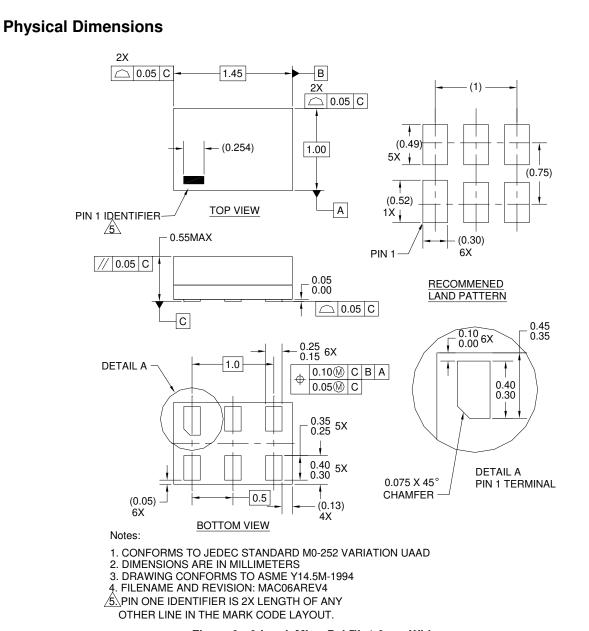


Figure 8. 5-Lead, SC70, EIAJ SC-88a, 1.25mm Wide

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P5X	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (Typical)	Empty	Sealed	





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Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status
	Leader (Start End)	125 (Typical)	Empty	Sealed
L6X	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (Typical)	Empty	Sealed

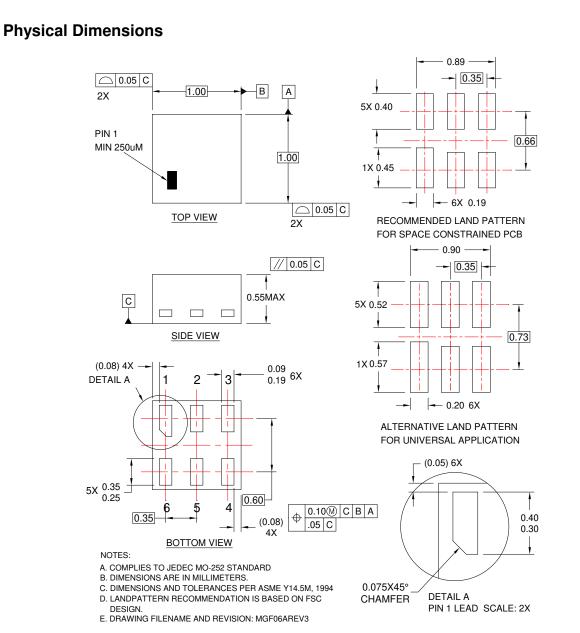


Figure 10. 6-Lead, MicroPak2, 1x1mm Body, .35mm Pitch

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Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status
FHX	Leader (Start End)	125 (Typical)	Empty	Sealed
	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (Typical)	Empty	Sealed

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